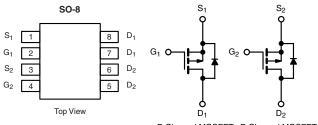
SQ4961EY



Vishay Siliconix

Automotive Dual P-Channel 60 V (D-S) 175 °C MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	- 60			
$R_{DS(on)} (\Omega)$ at $V_{GS} = -10 \text{ V}$	0.085			
$R_{DS(on)}(\Omega)$ at V_{GS} = - 4.5 V	0.115			
I _D (A) per leg	- 4.4			
Configuration	Dual			



P-Channel MOSFET P-Channel MOSFET

FEATURES

- TrenchFET[®] Power MOSFET
- AEC-Q101 Qualified
- 100 % R_g and UIS Tested
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>



ROHS COMPLIANT HALOGEN FREE

ORDERING INFORMATION				
Package	SO-8			
Lead (Pb)-free and Halogen-free	SQ4961EY-T1-GE3			

ABSOLUTE MAXIMUM RATINGS ($T_C = 25 \text{ °C}$, unless otherwise noted)					
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-Source Voltage		V _{DS}	- 60	V	
Gate-Source Voltage		V _{GS}	± 20	V	
Continuous Drain Current	T _C = 25 °C	L	- 4.4		
	T _C = 125 °C	I _D	- 2.5		
Continuous Source Current (Diode Conduction)		I _S	- 3	A	
Pulsed Drain Current ^a		I _{DM}	- 18		
Single Pulse Avalanche Current	L = 0.1 mH	I _{AS}	- 20		
Single Pulse Avalanche Energy		E _{AS}	20	mJ	
Maximum Power Dissipation ^a	T _C = 25 °C	D	3.3	w	
	T _C = 125 °C	P _D	1.1		
Operating Junction and Storage Temperature Ra	ange	T _J , T _{stg}	- 55 to + 175	°C	

THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	LIMIT	UNIT	
Junction-to-Ambient	PCB Mount ^b	R _{thJA}	105	°C/W	
Junction-to-Foot (Drain)		R _{thJF}	45	0/10	

Notes

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

b. When mounted on 1" square PCB (FR-4 material).

1 For technical questions, contact: <u>automostechsupport@vishay.com</u> www.vishay.com

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PARAMETER	SYMBOL	TES	MIN.	TYP.	MAX.	UNIT	
Static							
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 V, I_D = -250 \mu A$		- 60	-	-	v
Gate-Source Threshold Voltage	V _{GS(th)}	V _{DS} =	$V_{DS} = V_{GS}$, $I_D = -250 \ \mu A$		- 2.0	- 2.5	
Gate-Source Leakage	I _{GSS}	V _{DS} =	$V_{DS} = 0 V, V_{GS} = \pm 20 V$		-	± 100	nA
		$V_{GS} = 0 V$	V _{DS} = - 60 V	-	-	- 1	
Zero Gate Voltage Drain Current	I _{DSS}	$V_{GS} = 0 V$	$V_{DS} = -60 \text{ V}, \text{ T}_{J} = 125 ^{\circ}\text{C}$	-	-	- 50	μA
		$V_{GS} = 0 V$	$V_{DS} = -60 \text{ V}, \text{ T}_{J} = 175 ^{\circ}\text{C}$	-	-	- 150	
On-State Drain Current ^a	I _{D(on)}	V _{GS} = - 10 V	$V_{DS} \le$ - 5 V	- 12	-	-	Α
		V _{GS} = - 10 V	I _D = - 3.5 A	-	0.070	0.085	Ω
Drain Course On State Registeres	Р	V _{GS} = - 10 V	I _D = - 3.5 A, T _J = 125 °C	-	-	0.142	
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = -10 V$	I _D = - 3.5 A, T _J = 175 °C	-	-	0.176	
		V _{GS} = - 4.5 V	I _D = - 2.5 A	-	0.095	0.115	
Forward Transconductanceb	9 _{fs}	V _{DS} =	V _{DS} = - 15 V, I _D = - 3.5 A		9	-	S
Dynamic ^b	-						
Input Capacitance	C _{iss}			-	912	1140	pF
Output Capacitance	C _{oss}	$V_{GS} = 0 V$	V_{DS} = - 30 V, f = 1 MHz	-	100	125	
Reverse Transfer Capacitance	C _{rss}			-	60	75	
Total Gate Charge ^c	Qg			-	26.5	40	
Gate-Source Charge ^c	Q _{gs}	$V_{GS} = -10 V$	V $V_{DS} = -30$ V, $I_D = -4.3$ A	-	3.8	-	nC
Gate-Drain Charge ^c	Q _{gd}			-	5.8	-	
Gate Resistance	R _g	f = 1 MHz		3	-	16	Ω
Turn-On Delay Time ^c	t _{d(on)}			-	11	17	
Rise Time ^c	tr	$\label{eq:V_DD} \begin{array}{l} V_{\text{DD}} = -30 \ V, \ R_{\text{L}} = 8.8 \ \Omega \\ I_{\text{D}} \cong -3.4 \ A, \ V_{\text{GEN}} = -10 \ V, \ R_{g} = 1 \ \Omega \end{array}$		-	13	20	ns
Turn-Off Delay Time ^c	t _{d(off)}			-	36	54	
Fall Time ^c	t _f			-	8	12	
Source-Drain Diode Ratings and Characteristics ^b							
Pulsed Current ^a	I _{SM}			-	-	- 18	А
Forward Voltage	V _{SD}	I _F = - 3 A, V _{GS} = 0 V		-	- 0.84	- 1.2	V

Notes

a. Pulse test; pulse width \leq 300 $\mu s,$ duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

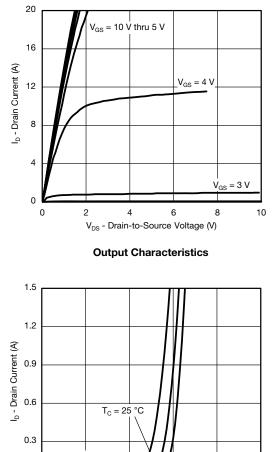
c. Independent of operating temperature.

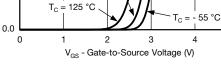
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

2



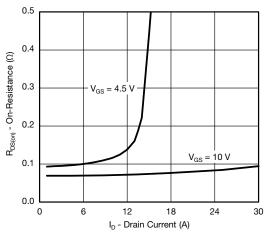
TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



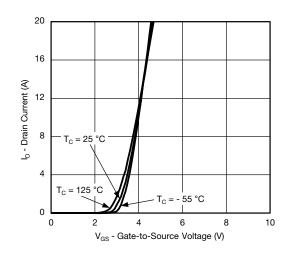


Transfer Characteristics

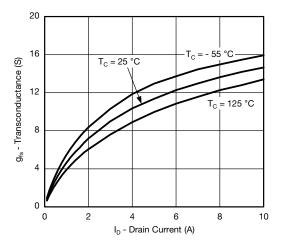
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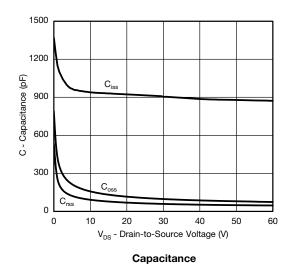
On-Resistance vs. Drain Current



Transfer Characteristics



Transconductance



S12-2907-Rev. B, 10-Dec-12

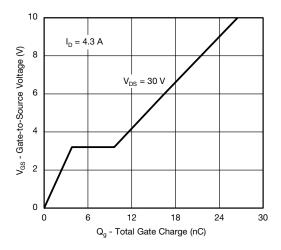
3

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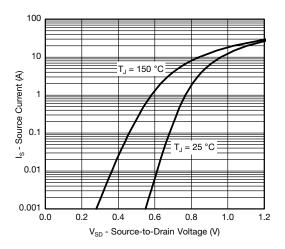
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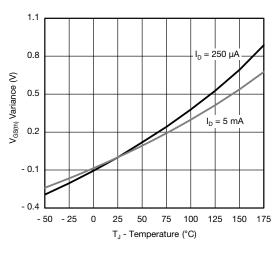
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



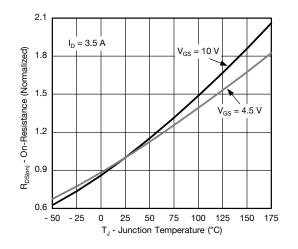
Gate Charge



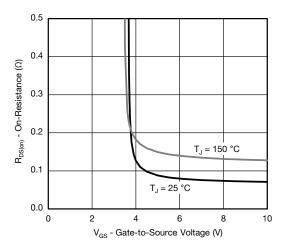
Source Drain Diode Forward Voltage

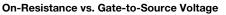


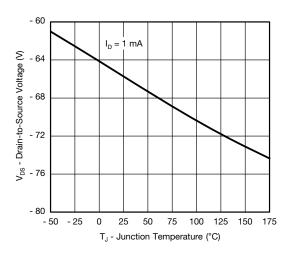
Threshold Voltage



On-Resistance vs. Junction Temperature







Drain Source Breakdown vs. Junction Temperature

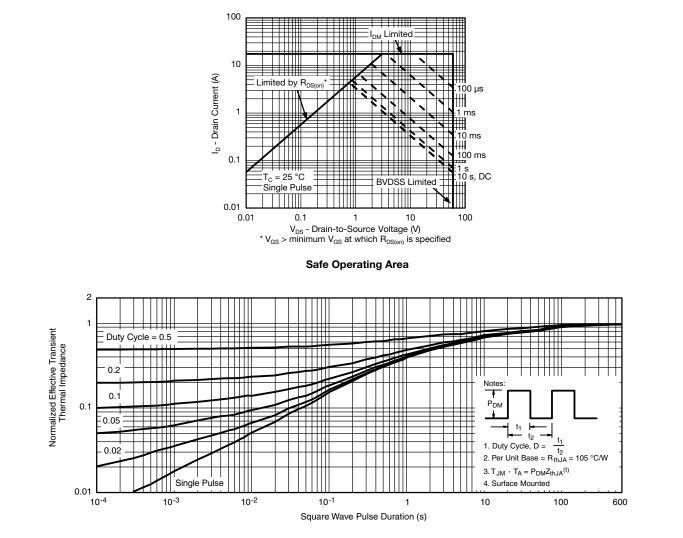
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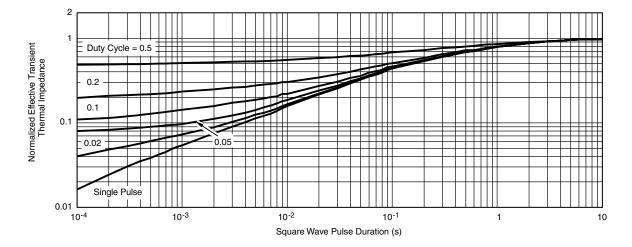
THERMAL RATINGS ($T_A = 25 \text{ °C}$, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Foot

Note

- The characteristics shown in the two graphs
- Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
- Normalized Transient Thermal Impedance Junction-to-Foot (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?67539.



Package Information

Vishay Siliconix

SOIC (NARROW): 8-LEAD JEDEC Part Number: MS-012





	MILLIM	IETERS	INCHES		
DIM	Min	Мах	Min	Max	
A	1.35	1.75	0.053	0.069	
A ₁	0.10	0.20	0.004	0.008	
В	0.35	0.51	0.014	0.020	
С	0.19	0.25	0.0075	0.010	
D	4.80	5.00	0.189	0.196	
E	3.80	4.00	0.150	0.157	
е	1.27	BSC	0.050 BSC		
н	5.80	6.20	0.228	0.244	
h	0.25	0.50	0.010	0.020	
L	0.50	0.93	0.020	0.037	
q	0°	8°	0°	8°	
S	0.44	0.64	0.018	0.026	
ECN: C-06527-Rev. I, 11-Sep-06 DWG: 5498					

Application Note 826

Vishay Siliconix



RECOMMENDED MINIMUM PADS FOR SO-8



Recommended Minimum Pads Dimensions in Inches/(mm)

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Revision: 01-Jan-2025

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